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Effects of O₂, H₂, and N₂ gases on the field emission properties of diamond-coated microtips

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We report the effects of O₂, H₂, and N₂ residual gases on the field emission properties of uncoated and diamond-coated individual Mo microtips. The microtips are made using electrochemical etching techniques and positioned 5 μm from the anode using a scanning tunneling microscopy system. We observe that the field emission (FE) current and turn-on voltage of diamond-coated microtips are significantly less degraded by O₂ exposure than those of uncoated Mo microtips. H₂ exposure enhances the FE properties of both uncoated and diamond-coated microtips, while N₂ exposure does not have any significant effect. © 1999 American Institute of Physics.

Electron field emission (FE) from cold cathodes has recently attracted considerable interest due to potential applications in flat panel displays (FPDs) and vacuum electronics. In order to achieve FE from the surface of a material, a very high electric field must be used. To enhance the electric field near the surface, the material may be sharpened into a microtip. Materials that are used as microtips should be able to endure extremely high electrical stresses, achieve a high aspect ratio, and have good thermal conductivity. As a result, refractory metals such as Mo are currently used as microtips. However, metal microtips react with residual gases in vacuum containers such as O₂ resulting in an increase in the work function of the surface. In addition, the electric field near the microtip is high enough to ionize residual gases and the resultant ion bombardment of the microtip eventually results in failure of the microtip.

Chemical vapor deposition (CVD) grown diamond has been reported to emit electrons at fields as low as 10 V/μm. A low field is advantageous in reducing ion formation and damage from ion bombardment. In addition, diamond is very inert and has a high thermal conductivity. Diamond coating of Si field emission arrays (FEAs) and individual Mo microtips, and diamond-like carbon coating of Mo FEAs have recently been reported to increase the FE current. The effects of Ne, He, H₂, and D₂ gases on the FE properties of diamond-coated Si microtips have been reported. In this letter, we report the effects of O₂, H₂, and N₂ on the FE properties of uncoated and diamond-coated individual Mo microtips.

The individual Mo microtips are made from Mo wire 0.020 in. in diameter using electrochemical etching techniques similar to those used in etching tips for scanning tunneling microscopy (STM). Typical etched Mo microtip apex diameters are <0.05 μm. To grow a diamond film on a Mo microtip, pre-seeding with 0.25 μm diamond powder is carried out using dielectrophoresis. To ensure that only the smaller particles of the average 0.25 μm diamond powder are in suspension, the solution is allowed to settle 1 h before dielectrophoresis. The seeded microtips are spot welded on a Mo wire and placed in a hot-tungsten filament CVD reactor. A thin diamond film is deposited for 60 min with a microtip temperature of 850 °C, and pressure of 30 Torr using H₂ and methane with flow rates of 200 and 1 sccm, respectively. The tungsten filament temperature is 2200 °C. Diborane at a concentration of 10 ppm relative to H₂ is introduced during growth to make the film conducting. The growth experiment is terminated by first shutting off the methane flow while maintaining the microtip, filament, and H₂ settings for 2 min.

The inchworm is housed in a vacuum system equipped with a quadrupole mass spectrometer at a base pressure ≈10⁻⁹ Torr. A microtip is loaded on the inchworm and the system is operated in STM mode. An atomically flat highly oriented pyrolytic graphite surface is used as the anode. The microtip approaches the anode until tunneling occurs at a...
tip-anode distance of 0.5–1.0 nm. The microtip is then retracted a distance of 5.00 ± 0.02 μm from the anode using the inchworm, and the STM feedback electronics are disengaged. Separate high-voltage electronics are used to measure the FE current versus voltage (I–V) curves. The microtip is cleaned of adsorbates in vacuum by biasing the microtip at a voltage of 500 V and FE current of 1.3 × 10⁻² A for about 24 h until the variation in the FE current is less than 1%.

Before O₂ exposure, FE I–V curves are measured at a pressure ≤ 10⁻⁹ Torr, as shown in Fig. 2 for 0 L exposure. In Fig. 2, the FE data are plotted ln(I/V²) vs 1/V to allow comparison with the straight-line behavior predicted for FE by the FN equation. The inset in Fig. 2 shows the I–V curves plotted using a log-linear scale. The small current on the order of 10⁻¹¹ A observed below the threshold voltage for FE is due to leakage across the connectors. To achieve 1 L of exposure, O₂ is introduced into the vacuum system to a pressure of 2 × 10⁻⁷ Torr and the microtip is biased at a voltage that produces a FE current of 1 × 10⁻⁶ A for 5 s. After this exposure, the vacuum system is evacuated to ≤ 10⁻⁹ Torr and FE I–V curves are measured, as shown in Fig. 2 for 1 L of exposure. In this manner, the microtip is not exposed to O₂ during the I–V curve measurement. To achieve 10 L of exposure, O₂ is introduced again into the vacuum system to a pressure of 2 × 10⁻⁷ Torr and the microtip is biased at the same voltage for 50 s. Then, the system is evacuated to ≤ 10⁻⁹ Torr and the FE I–V curves are measured, as shown in Fig. 2 for 10 L of exposure. This procedure is repeated for 100 and 1000 L of exposure.

As shown in Fig. 2(a), exposure of an uncoated Mo microtip to O₂ results in a decrease in the FE current, an effect that begins to appear after 1 L of exposure. Significant decrease in the FE current occurs after 100 L of exposure. After 1000 L of exposure, the FE current has completely disappeared. Before exposure, the FE current is approximately 2 × 10⁻⁶ A at 550 V. After 100 L of exposure, the FE current at this voltage decreases to approximately 7 × 10⁻¹¹ A, a decrease of almost four orders of magnitude. As the O₂ exposure increases from 0 to 100 L, the turn-on voltage increases from approximately 300 to 525 V. Figure 2(b) shows the FE I–V curves of a diamond-coated Mo microtip after exposure to O₂. Exposure to 1 L of O₂ decreases the FE current at 400 V from 2 × 10⁻⁷ to 5 × 10⁻⁸ A, a decrease of about a factor of 4. Subsequent exposures decrease the FE current at
400 V to as low as $1 \times 10^{-8}$ A. The turn-on voltage increases from about 250 to 300 V. By comparison, the FE current of an uncoated Mo microtip at 550 V decreases by almost four orders of magnitude after 100 L of exposure, and completely turns off after 1000 L of exposure.

As shown in Fig. 3(a), exposure of an uncoated Mo microtip to 1 L of H$_2$ results in an increase in FE current from $3 \times 10^{-9}$ to $6 \times 10^{-7}$ A at a tip bias of 550 V, and a significant reduction in turn-on voltage. This observation is consistent with reports of an increase in FE current from Mo FEAs after H$_2$ exposure. After exposures of 10 and 100 L, the FE current at a bias of 550 V does not significantly change. As shown in Fig. 3(b), exposure of a diamond-coated Mo microtip to 1 L of H$_2$ results in an increase in the FE current and decrease in the turn-on voltage. After subsequent exposures, the FE current and turn-on voltage continue to increase and decrease, respectively. After 100 L of exposure, the FE current at 160 V has increased from $3 \times 10^{-9}$ to $1 \times 10^{-6}$ A. After 1 L of exposure, an increase in current below the threshold voltage for FE is observed, indicated by the arrow in Fig. 3(b). This type of current observed below threshold after H$_2$ exposure has been previously reported and attributed to a hydrogen overlayer.

As shown in Fig. 4(a), exposure of an uncoated Mo microtip to 1 L of N$_2$ results in an increase in the turn-on voltage and a slight decrease in the FE current. After subsequent exposures, very little change in the FE current near maximum current is observed. As shown in Fig. 4(b), exposure of a diamond-coated microtip to N$_2$ results in less change than that observed for an uncoated Mo microtip in Fig. 4(a). We conclude that at the exposures and tip-anode distances used, nitrogen ion sputtering does not significantly affect the FE properties of uncoated or diamond-coated Mo microtips.

In summary, we report that the FE properties of diamond-coated Mo microtips are significantly less degraded by O$_2$ exposure than those of uncoated Mo microtips. H$_2$ exposure significantly increases the FE current from uncoated and diamond-coated Mo microtips. N$_2$ exposure does not have a significant effect on the FE properties of uncoated or diamond-coated microtips, but degrades the properties of diamond-coated microtips less than those of uncoated microtips.

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